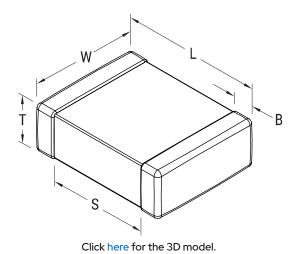




KC-LINK Comm COG, Ceramic, 0.027 uF, 2%, 1,000 VDC, COG, SMD, MLCC, FT-CAP, Ultra-Stable, 2220



General Information	
Series	KC-LINK Comm COG
Style	SMD Chip
Description	SMD, MLCC, FT-CAP, Ultra- Stable
Features	FT-CAP, Ultra-Stable
RoHS	Yes
Termination	Flexible Termination
Marking	No
AEC-Q200	No
Typical Component Weight	260 mg
Shelf Life	78 Weeks
MSL	1

ns Specifications Specifications Capacitance Capacitan			
5.9mm +/-0.75mm     Measurement Condition       5mm +/-0.4mm     Tolerance       2mm +/-0.20mm     Voltage DC       0.7mm +/-0.35mm     Dielectric Withstand       Temperature Range     Temperature Range	าร		Specifications
5mm +/-0.4mm     Tolerance       2mm +/-0.20mm     Voltage DC       0.7mm +/-0.35mm     Dielectric Withstand       Temperature Range		2220	Capacitance
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0.7mm +/-0.35mm Dielectric Withstand Temperature Range		5mm +/-0.4mm	Tolerance
Temperature Range		2mm +/-0.20mm	Voltage DC
Specifications		0.7mm +/-0.35mm	Dielectric Withstand
Specifications Temp. Coefficient			Temperature Range
	g Specifications		Temp. Coefficient

Packaging Specifications	
Packaging	T&R, 330mm, Plastic Tape
Packaging Quantity	2000

Specifications	
Capacitance	0.027 uF
Measurement Condition	1 kHz 1.0Vrms
Tolerance	2%
Voltage DC	1000 VDC
Dielectric Withstanding Voltage	1,200 VDC
Temperature Range	-55/+150°C
Temp. Coefficient	COG
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1kHz 1.0Vrms
Dissipation Factor	0.1% 1 kHz 1.0Vrms
Aging Rate	0% Loss/Decade Hour
Insulation Resistance	37.037 GOhms

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

Dimension Chip Size

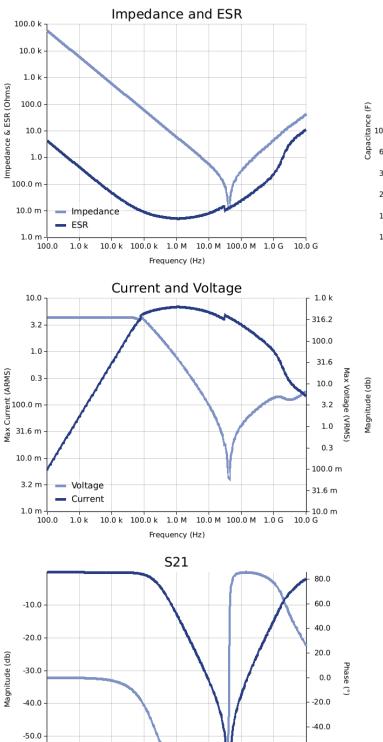
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CKC21X273GDGAC7210 KC-LINK Comm COG, Ceramic, 0.027 uF, 2%, 1,000 VDC, COG, SMD, MLCC, FT-CAP, Ultra-Stable, 2220

## Simulations

For the complete simulation environment please visit Y-SIM.



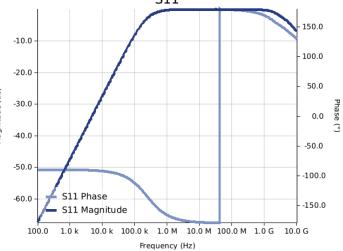
1.0 k 10.0 k 100.0 k 1.0 M 10.0 M 100.0 M 1.0 G 10.0 G

Frequency (Hz)

-60.0

-80.0

Capacitance and Inductance 1.0 µ 1.0 n 0.6 n 0.6 μ 0.4 μ 0.4 n 0.3 μ 0.3 n 4 2.0 (E Gabacitance (E) 100.0 n 63.1 n 0.2 n a 100.0 p 63.1 p 🗄 39.8 n 39.8 p 25.1 n 25.1 p Inductance 15.8 n 15.8 p Capacitance 10.0 p 100.0 M 10.0 n 10.0 k 1.0 M 1.0 k 100.0 k 10.0 M 100.0 Frequency (Hz) S11



100.0

-60.0

S21 Phase

S21 Magnitude



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## These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for https:// temperature Rise vs. Ripple Current/ voltage vs. Frequency plots is the ESR at ambient temperature.
  The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
  The effects shown herein are based on measured data from a multiple part sample of the parts in question.
  Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
  The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.
  Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.